

S22MD1V/S22MD3

Photothyristor Coupler

* Lead forming type (I type) and taping reel type (P type) of **S22MD1V** are also available (**S22MD1V/S22MD1P**)

** TÜV (DIN-VDE0884) approved type is also available as an option.

■ Features

1. High repetitive peak OFF-state voltage
(V_{DRM} : MIN. 600V)
2. Low trigger current
(I_{FT} : MAX. 10mA at $R_G = 20k\Omega$)
3. High isolation voltage between input and output

S22MD1V ... V_{iso} : 5 000V_{rms}

S22MD3V ... V_{iso} : 2 500V_{rms}

* **S22MD1V** and **S22MD3** are for 200V line.

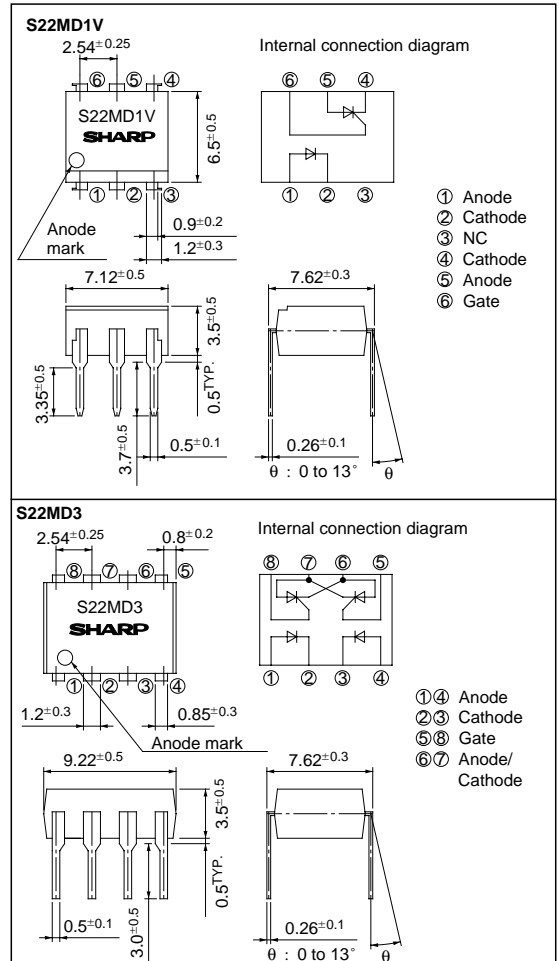
4. Recognized by UL, file NO. 64380

■ Applications

1. ON-OFF operation for a low power load
2. For triggering high power thyristor and triac

■ Outline Dimensions

(Unit : mm)



Absolute Maximum Ratings

(Ta = 25°C)

Parameter		Symbol	Rating		Unit
			S22MD1V	S22MD3	
Input	Forward current	I _F	50		mA
	Reverse voltage	V _R	6		V
Output	RMS ON-state current	I _T	200		mA _{rms}
	*1Peak one cycle surge current	I _{surge}	2		A
	*2Repetitive peak OFF-state voltage	V _{DRM}	600		V
	*2Repetitive peak reverse voltage	V _{RRM}	600	-	V
*3Isolation voltage		V _{iso}	5 000	2 500	V _{rms}
Operating temperature		T _{opr}	-30 to +100	-30 to +100	°C
Storage temperature		T _{stg}	-55 to +125	-40 to +125	°C
*4Soldering temperature		T _{sol}	260		°C

*1 50H z, sine wave

*2 R_G = 20kΩ

*3 40 to 60% RH, AC for 1 minute

*4 For 10 seconds

Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 30mA	-	1.2	1.4	V
	Reverse current	I _R	V _R = 3V	-	-	10 ⁻⁵	A
Output	Repetitive peak OFF-state current	I _{DRM}	V _{DRM} = Rated, R _G = 20kΩ	-	-	10 ⁻⁶	A
	*5Repetitive peak reverse current	I _{RRM}	V _{RRM} = Rated, R _G = 20kΩ	-	-	10 ⁻⁶	A
	ON-state voltage	V _T	I _T = 200mA	-	1.0	1.4	V
	Holding current	I _H	V _D = 6V, R _G = 20kΩ	-	0.2	1	mA
	Critical rate of rise of OFF-state voltage	dV/dt	V _{DRM} = 1/√2 Rated, R _G = 20kΩ	5	-	-	V/μs
	3			-	-		
Transfer characteristics	Minimum trigger current	I _{FT}	V _D = 6V, R _L = 100Ω, R _G = 20kΩ	-	-	10	mA
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω
	Turn-on time	t _{on}	V _D = 6V, R _G = 20kΩ, R _L = 100Ω, I _F = 30mA	-	20	50	μs

*5 Applies only to S22MD1V

Fig. 1 RMS ON-state Current vs. Ambient Temperature

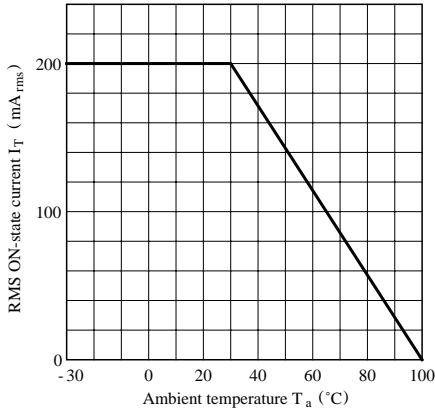


Fig. 2 Forward Current vs. Ambient Temperature

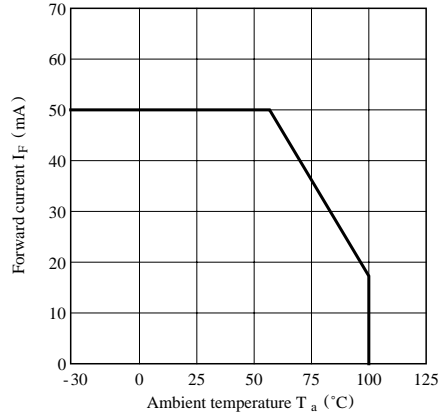


Fig. 3 Forward Current vs. Forward Voltage

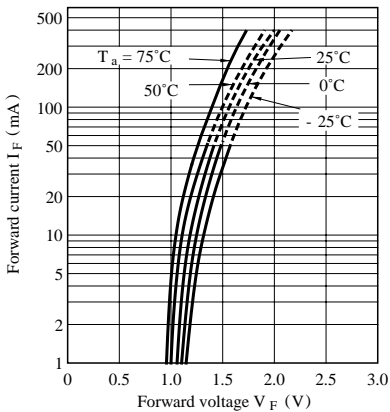


Fig. 4 Minimum Trigger Current vs. Ambient Temperature

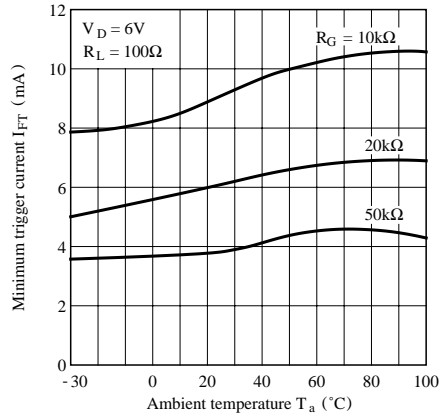


Fig. 5 Minimum Trigger Current vs. Gate Resistance

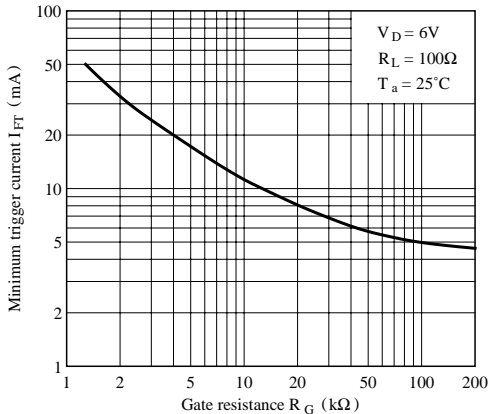


Fig. 6 Break Over Voltage vs. Ambient Temperature

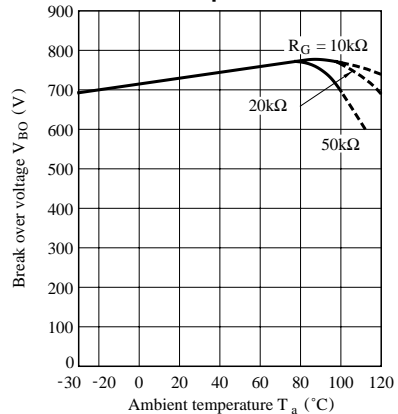


Fig. 7 Critical Rate of Rise of OFF-state Voltage vs. Ambient Temperature

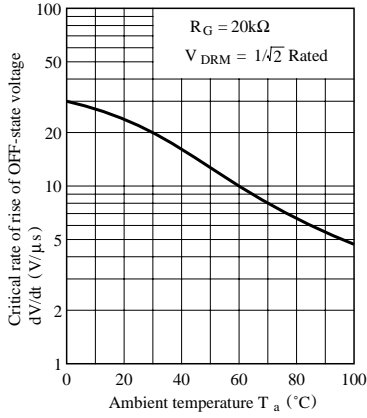


Fig. 8 Holding Current vs. Ambient Temperature

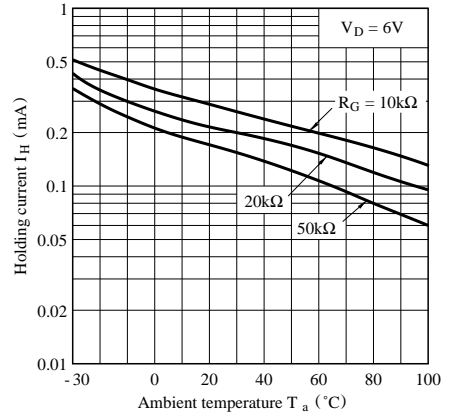
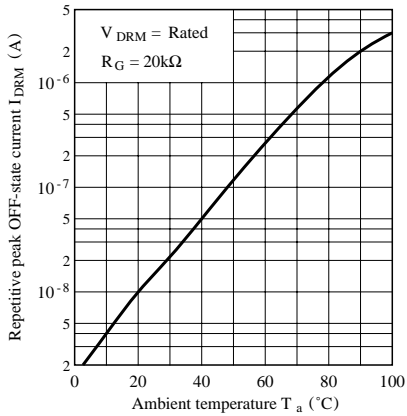


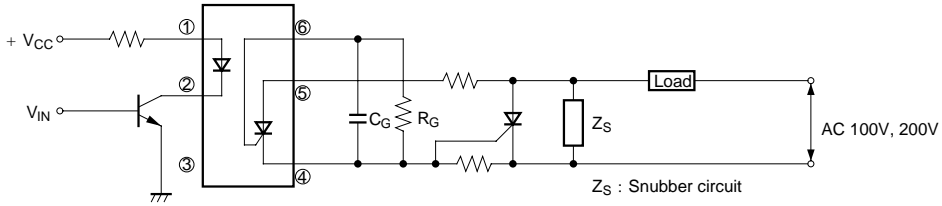
Fig. 9 Repetitive Peak OFF-state Current vs. Ambient Temperature



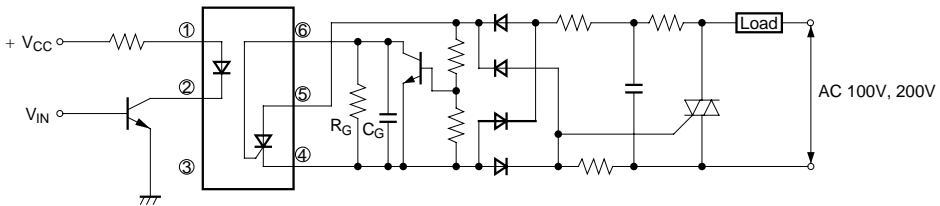
■ Basic Operation Circuit

● S22MD1V

Medium/High Power Thyristor Drive Circuit

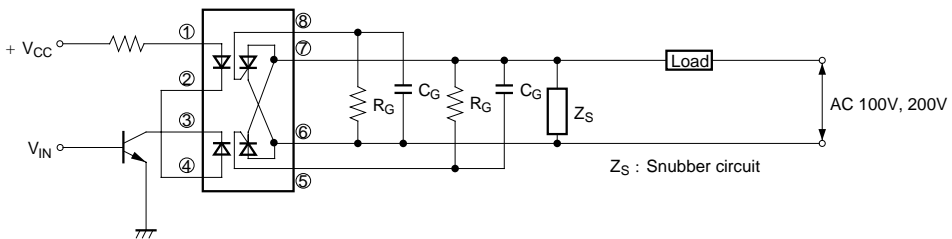


Medium/High Power Triac Drive Circuit (Zero-cross Operation)

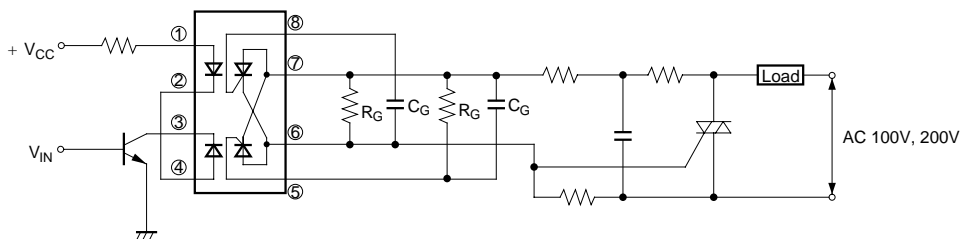


● S22MD3

Low Power Load Drive Circuit



Medium/High Power Triac Drive Circuit



● Please refer to the chapter “Precautions for Use” (Page 78 to 93).

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